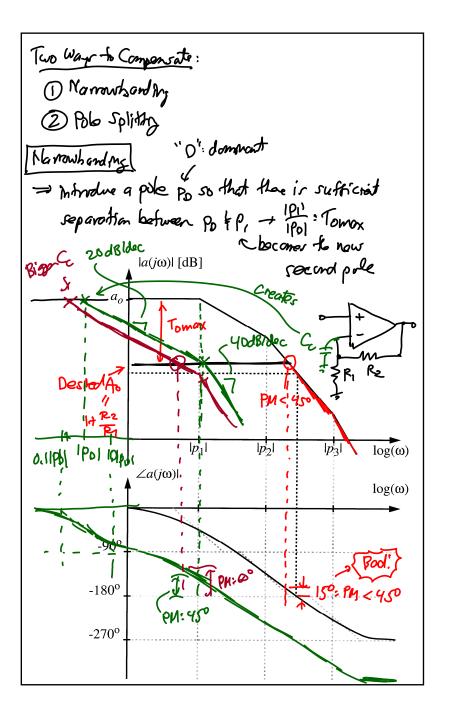
<u>Lecture 20w</u>: Choosing Cc

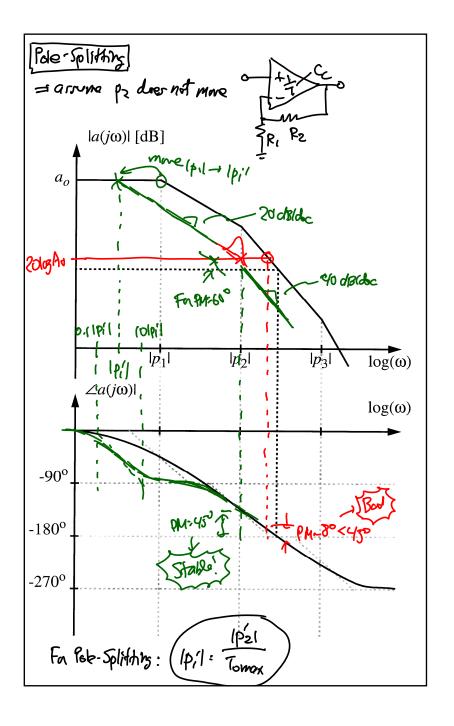
Lecture 20: Choosing Cc Announcements: Lab#2 due this week HW#9 online Lab#3 (Design Project) in progress Design Project Checkpoint: ♦ Due Tuesday, Nov. 19, 11:59 p.m. Send to your TA a spice file for your op amp design that simulates correctly, i.e., that reaches a stable bias point where all transistors are saturated (or linear if an MOS resistor) \$It doesn't need to meet the project specs, but it should simulate correctly · Lecture Topics: **♥** Compensation ♦ Choosing Cc Last Time: Compensation laciwilds 1 20 (03 (A) 100(0) 20103 (Tomas): -20(103(P2)-103(P1)) - Fa AM245° 1P21 : Tomax - 1P21: 1P11 Tomax



EE 140/240A: Analog Integrated Circuits

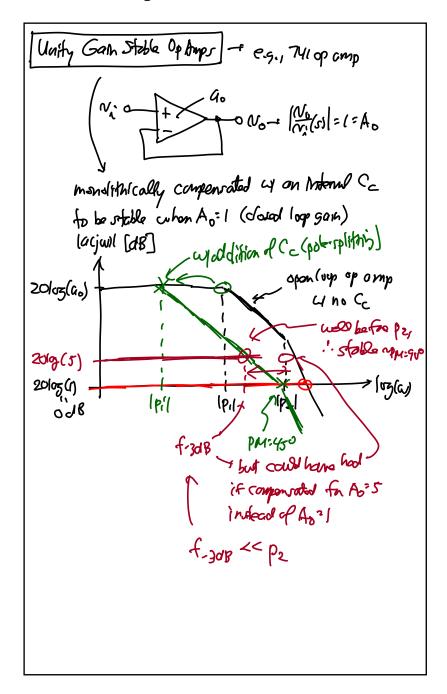
<u>Lecture 20w</u>: Choosing Cc

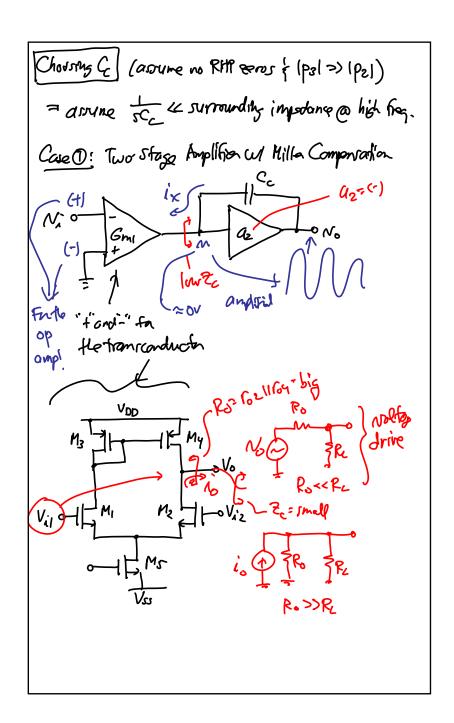
Remarks on Narrow banding 1 1) Assumption: P1, P2, P3 dait more when Po is Minduod (often not true, but their mound isn't that big) 2) Summarize choose PD such that [T(jw)= OdB=1@p, (which becomes the "new 2" most dominant pole") 4 this gives PM=450 (for 1p21 >> 1p,1 is 1p31 >> 1p21) 3 Why do this? Wouldn't it be mud better to just more the original IPII (i.e., pole-split) & Do it when you have no other choice, e.g., when you have a pockaged opening & hore access only to a few termonals, not the optimum componsation node. [PD] = Tomax (maximum expectalinedal Problemi O often, IPDI << IPI : f-3de BW of the or our will be very mult 2 Would loop = IPI which isn't that large Solution: Pole-splitting more ipil down t either leep Ipel still u mare Ipel up simultaneously after doing this: 1 W-3dB = 1Pil (2) Wdordby = 1Pil



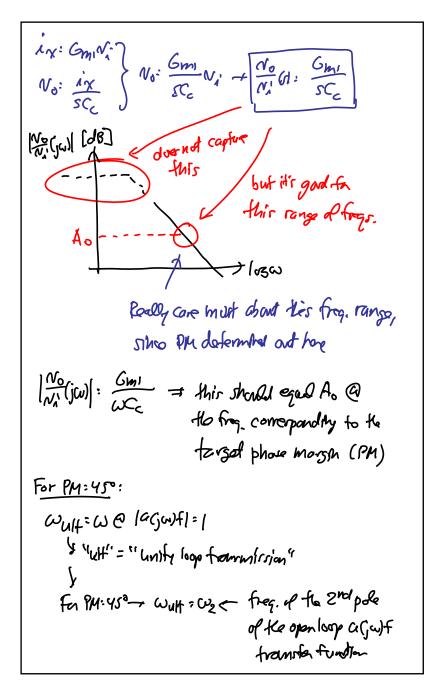
EE 140/240A: Analog Integrated Circuits

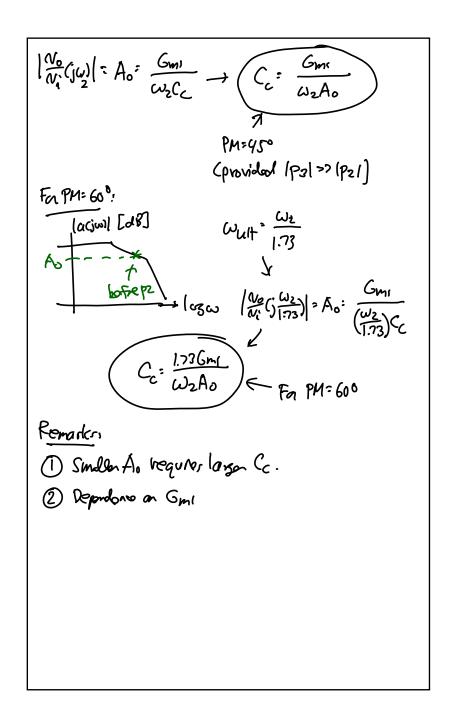
<u>Lecture 20w</u>: Choosing Cc



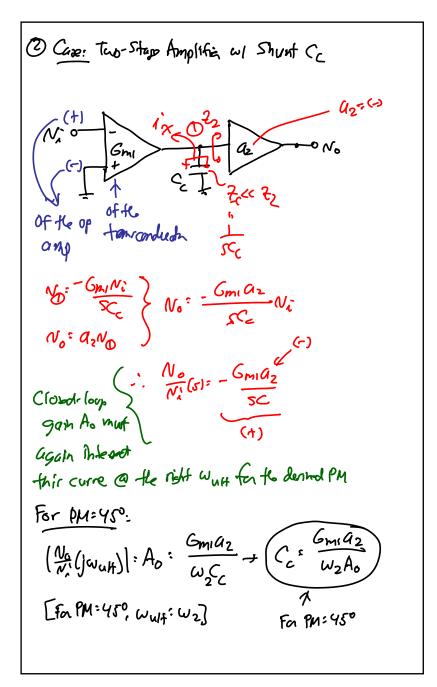


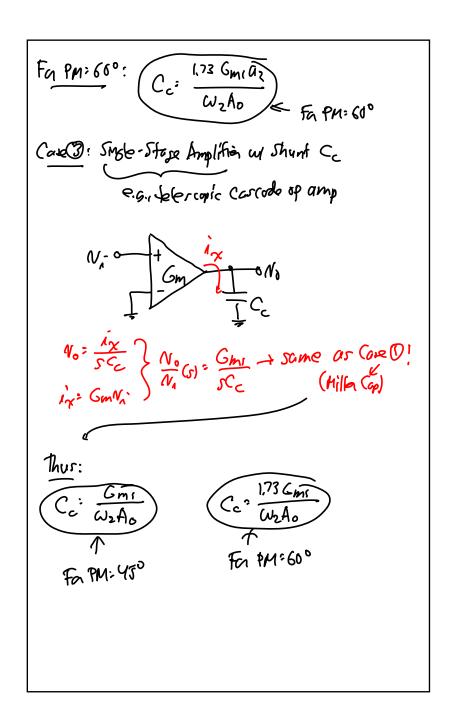
Lecture 20w: Choosing Cc





<u>Lecture 20w</u>: Choosing Cc





Lecture 20w: Choosing Cc

